- Short-Circuit Protection
- Wide Common-Mode and Differential Voltage Ranges
- No Frequency Compensation Required
- Low Power Consumption
- No Latch-Up
- Designed to Be Interchangeable With Motorola MC1558/MC1458 and Signetics S5558/N5558

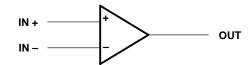
description

The MC1458 and MC1558 are dual generalpurpose operational amplifiers with each half electrically similar to the μ A741 except that offset null capability is not provided.

The high-common-mode input voltage range and the absence of latch-up make these amplifiers ideal for voltage-follower applications. The devices are short-circuit protected and the internal frequency compensation ensures stability without external components.

The MC1458 is characterized for operation from 0°C to 70°C. The MC1558 is characterized for operation over the full military temperature range of -55° C to 125°C.

symbol (each amplifier)



MC1458 D OR P PACKAGE MC1558 JG PACKAGE (TOP VIEW)							
10UT [1 1IN – [2 1IN + [3 V _{CC} – [4	8] V _{CC} + 7] 2OUT 6] 2IN – 5] 2IN +						
MC1558 U (TOP V							
NC [• 1 1OUT [2 1IN - [3 1IN + [4 V _{CC} - [5 MC1558 FF	10 NC 9 V _{CC} + 8 2OUT 7 2IN – 6 2IN +						
(TOP V	IEW)						
NC 10 NC 4 10 10 10 10 10 10 10 10 10 10	+ 20 19 18 17 20 UT 18 17 20UT 16 NC 15 20UT 16 NC 15 20UT 18 NC 17 20UT 18 NC 17 20UT 18 NC 17 20UT 18 NC 17 20UT 18 NC 17 20UT 18 NC 17 20UT 18 NC 17 20UT 18 NC 17 20UT 18 NC 17 20UT 18 NC 17 20UT 18 NC 15 20N NC 15 20N NC 15 20N NC 15 20N NC 15 20N NC 15 20N NC 15 20N NC 15 20N NC 15 20N NC 15 20N NC 15 20N NC 15 20N NC 15 20N NC 15 20N NC 15 20N NC 15 10 NC 15 20N NC 14 NC 15 10 NC 15 NC 15 NC 15 NC 15 NC 15 NC 15 NC 15 NC 15 NC 15 NC 15 NC 10 NC 15 NC 10 NC 10 NC 15 NC 10 NC 10 NC 10 NC 10 NC						

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NC - No internal connection

AVAIL	OPT	IONS

				PACKAGE		
T _A	V _{IO} max AT 25°C	SMALL OUTLINE (D)	CHIP CARRIER (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)	CERAMIC FLAT PACK (U)
0°C to 70°C	6 mV	MC1458CD	-		MC1458CP	—
-55°C to 125°C	5 mV	_	MC1558MFK	MC1558MSG		MC1558MU

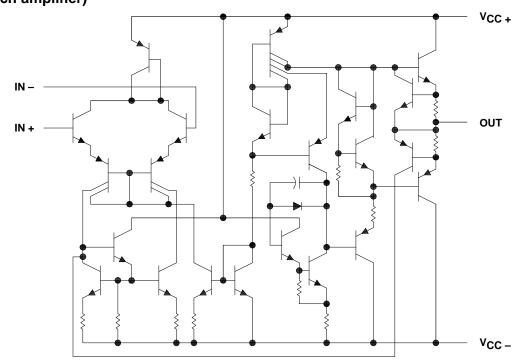
The D packages are available taped and reeled. Add the suffix R to the device type (i.e., MC1458DR)

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.



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schematic (each amplifier)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

		MC1458	MC1558	UNIT
Supply voltage V _{CC} + (see Note 1)		18 22 V		
Supply voltage V _{CC} – (see Note 1)	-18	-22	V	
Differential input voltage (see Note 2)	±30	±30	V	
Input voltage at either input (see Notes 1 and 3)	±15	±15	V	
Duration of output short circuit (see Note 4)		unlimited	unlimited	
Continuous total dissipation		See Dissipation Rating Table		
Operating free-air temperature range		0 to 70	-55 to 125	°C
Storage temperature range		65 to 150	-65 to 150	°C
Case temperature for 60 seconds: FK package			260	°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	JG or U package		300	°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	D or P package	260		°C

NOTES: 1. All voltage values, unless otherwise noted, are with respect to the midpoint between V_{CC +} and V_{CC -}.

2. Differential voltages are at IN+ with respect to IN-.

3. The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 V, whichever is less.

4. The output can be shorted to ground or either power supply. For the MC1558 only, the unlimited duration of the short circuit applies at (or below) 125°C case temperature or 70°C free-air temperature.

DISSIPATION RATING TABLE

PACKAGE	T _A ≤ 25°C POWER RATING	DERATING FACTOR	DERATE ABOVE T _A	T _A = 70°C POWER RATING	T _A = 125°C POWER RATING						
D	680 mW	5.8 mW/°C	33°C	464 mW	_						
FK	680 mW	11.0 mW/°C	88°C	880 mW	275 mW						
JG	680 mW	8.4 mW/°C	69°C	672 mW	210 mW						
Р	680 mW	8.0 mW/°C	65°C	640 mW	_						
U	675 mW	5.4 mW/°C	25°C	432 mW	135 mW						



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recommended operating conditions

	MIN	NOM MAX	UNIT
Supply voltage, V _{CC\pm}	±5	±15	V

electrical characteristics at specified free-air temperature, V_{CC \pm} = ±15 V

		TEST CONDITIONS		Γ	AC1458		Ν	MC1558		116117
	PARAMETER	TEST CONDITIO	NSI	MIN	TYP	MAX	MIN	TYP	MAX	
Vio	Input offset voltage	V _O = 0	25°C		1	6		1	5	mV
VIO	input onset voltage	vO = 0	Full range			7.5			6	IIIV
li o	Input offset current	$V_{\Omega} = 0$	25°C		20	200		20	200	nA
IO	input onset current	vO = 0	Full range			300			500	ΠA
lun.	Input bias current	$V_{O} = 0$	25°C		80	500		80	500	nA
IВ	input bias current	v0 = 0	Full range			800			1500	
VICR	Common-mode input		25°C	±12	±13		±12	±13		v
VICR	voltage range		Full range	±12			±12			v
		R _L = 10 kΩ	25°C	±12	±14		±12	±14		
\/	Maximum peak output	$R_L \ge 10 \ k\Omega$	Full range	±12			±12			.,
VOM	DM voltage swing	$R_L = 2 k\Omega$	25°C	±10	±13		±10	±13		V
		$R_L \ge 2 k\Omega$	Full range	±10			±10			
٨	Large-signal differential	$R_1 \ge 2 k\Omega$,	25°C	20	200		50	200		V/mV
AVD	voltage amplification	$V_0 = \pm 10 V$	Full range	15			25			
B _{OM}	Maximum-output-swing bandwidth (closed loop)	$\label{eq:RL} \begin{split} &R_L = 2 \; k \Omega, \\ &V_O \geq \pm 10 \; V, \\ &A_{VD} \; = \; 1, \\ &THD \geq 5\% \end{split}$	25°C		14			14		kHz
B ₁	Unity-gain bandwidth		25°C		1			1		MHz
φm	Phase margin	A _{VD} = 1	25°C		65			65		°C
	Gain margin		25°C		11			11		dB
r _i	Input resistance		25°C	0.3*	2		0.3*	2		MΩ
r _o	Output resistance	V _O = 0, See Note 5	25°C		75			75		Ω
Ci	Input capacitance	_	25°C		1.4			1.4		pF
z _{iC}	Common-mode input impedance	f = 20 Hz	25°C		200			200		MΩ
CMPP	Common mode rejection ratio	VIC = VICR min,	25°C	70	90		70	90		dP
CMRR	Common-mode rejection ratio	$V_0 = 0$	Full range	70			70			dB
kova	Supply voltage sensitivity	$V_{CC} = \pm 9 V \text{ to } \pm 15 V,$	25°C		30	150		30	150	
ksvs	$(\Delta V_{IO}/\Delta V_{CC})$	$V_0 = 0$	Full range			150			150	μV/V
Vn	Equivalent input noise voltage (closed loop)	A _{VD} = 100, R _S = 0, f = 1 kHz, BW = 1 Hz	25°C		45			45		nV/√H

*This parameter is not production tested.

[†] All characteristics are specified under open-loop operating conditions with zero common-mode input voltage unless otherwise specified. Full range for MC1458 is 0°C to 70°C and for MC1558 is –55°C to 125°C.

NOTE 5: This typical value applies only at frequencies above a few hundred hertz because of the effect of drift and thermal feedback.



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electrical characteristics at specified free-air temperature, $V_{\mbox{CC}\pm}$ = ± 15 V (continued)

PARAMETER		TEST CONDITIONS [†]		MC1458			MC1558			UNIT
		TEST COND	MIN	TYP	MAX	MIN	TYP	MAX	UNIT	
IOS	Short-circuit output current		25°C		±25	±40		±25	±40	mA
100	ICC Supply current (both amplifiers)	$V_{\Omega} = 0$, No load	25°C		3.4	5.6		3.4	5	mA
ICC	Supply current (both ampliners)	$V_0 = 0$, No load	Full range			6.6			6.6	
De	Total power dissipation	$V_{\Omega} = 0$, No load	25°C		100	170		100	150	mW
PD	(both amplifiers)	$V_{O} = 0$, No load	Full range			200			200	IIIVV
V ₀₁ /V ₀₂	Crosstalk attenuation		25°C		120			120		dB

[†] All characteristics are specified under open-loop operating conditions with zero common-mode input voltage unless otherwise specified. Full range for MC1458 is 0°C to 70°C and for MC1558 is –55°C to 125°C.

operating characteristics, V_{CC\pm} = ± 15 V, T_A = 25°C

PARAMETER		TEST CONDITIONS		MC1458			MC1558			UNIT	
	PARAMETER		TEST CONDITIONS		TYP	MAX	MIN	TYP	MAX	UNIT	
t _r	Rise time	V _I = 20 mV,	$R_L = 2 k\Omega$,		0.3			0.3		μs	
	Overshoot factor	C _L = 100 pF,	See Figure 1		5%			5%			
SR	Slew rate at unity gain	V _I = 10 V, C _L = 100 pF,	R _L = 2 kΩ, See Figure 1		0.5			0.5		V/µs	



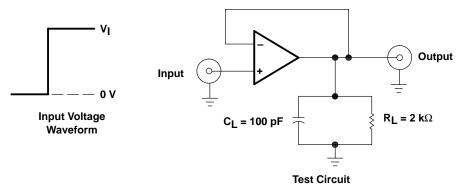


Figure 1. Rise Time, Overshoot, and Slew Rate Waveform and Test Circuit



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